

Printed Pages—4

TEE—403

(Following Paper ID and Roll No. to be filled in your Answer Book)

PAPER ID : 2053

Roll No.

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B.Tech.

FOURTH SEMESTER EXAMINATION, 2005-2006

**ELECTRICAL AND ELECTRONICS
ENGINEERING MATERIALS**

Time : 3 Hours

Total Marks : 100

- Note :**
- (i) Attempt **ALL** questions.
 - (ii) All questions carry equal marks.
 - (iii) In case of numerical problems assume data wherever not provided.
 - (iv) Be precise in your answer.

1. Attempt *any four* parts of the following : (5×4=20)

- (a) What is atomic radius ? Calculate for
 - (i) Simple cubic structure
 - (ii) Body centred cubic structure and
 - (iii) Face centred cubic structure.
- (b) Explain in brief :
 - (i) Unit cell
 - (ii) Space lattice and
 - (iii) Co-ordination number
- (c) Derive an expression for Bragg's law.

- (d) What is Miller Indices ? Explain the procedure for finding Miller Indices.
- (e) Explain with diagrams point, line and surface imperfections.
- (f) Explain the various electron energy bands in solids. Based on these bands distinguish between insulators conductors and semiconductors.

2. Attempt *any four* parts of the following : (5x4=20)

- (a) What is super conductivity ? How it is affected by
 - (i) frequency
 - (ii) magnetic field.
- (b) Determine the temperature coefficient of resistance of material used in a resistor if the resistance at 25°C is 50 ohms and at 70°C is 57.2 ohms.
- (c) Enumerate the characteristics of a good conductor. Discuss the effects of various factors on resistivity of a conductor.
- (d) Explain thermoelectric effects and materials suitable for making thermocouples.
- (e) Explain in brief the various electron theory of solids.
- (f) Derive an expression for heat development in a current carrying coil.

3. Attempt *any two* parts of the following : (10x2=20)

- (a) What is polarization in dielectric materials ?
Derive the relation $P = \epsilon_0 (\epsilon_r - 1) E$?

- (b) Discuss the following :
 - (i) Electronic polarization
 - (ii) Ionic polarization
 - (iii) Orientation polarization.
- (c) (i) Explain the phenomenon of piezo electricity
- (ii) Define the terms dielectric loss and loss angle of a dielectric ? Deduce expression.

4. Attempt *any two* parts of the following : (10x2=20)

- (a) (i) Discuss the mechanisms of conduction in N-type and P-type semiconductors.
- (ii) Differentiate between intrinsic and extrinsic semiconductors.
- (b) Explain the working principle of a FET. What is the difference between FET and BJT ? Explain why a low power FET is called as a square law device.
- (c) Explain the Hall effect. Show that the Hall coefficient is inversely proportional to the number of charge carriers density.

The resistivity of semi conductor material was known to be $0.00912 \Omega \text{ m}$ at room temperature. The flux density in the Hall model was 0.48 wb/m^2 .

Calculate the Hall angle for a Hall coefficient of $3.55 \times 10^{-4} \text{ m}^3/\text{coloumb}$.

5. Attempt *any two* parts of the following : (10x2=20)

- (a) Distinguish between soft and hard magnetic materials. Discuss and explain typical B-H curve for soft magnetic material.
- (b)
 - (i) What is magnetostriction ? How many types are possible ?
 - (ii) What are ferrites ? Give their properties.
- (c)
 - (i) State the desirable properties of high resistivity materials.
 - (ii) Enumerate and describe the general considerations for the selection of materials.

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